## NSN 5961-01-389-7916

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-389-7916 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.078 inches and 0.086 inches **Overall Height:** Between 0.034 inches and 0.044 inches **End Application:** Pacer dawn **Mounting Method:** Press fit **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakover voltage, dc **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Esd; junction pattern arrangement: nip **Terminal Type And Quantity:** 1 case and 1 ferrule Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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